NSN 5962-01-367-1275

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-367-1275

Body	Length:
------	---------

Between 1.050 inches and 1.070 inches

Body Width:

Between 0.300 inches and 0.320 inches

Body Height:

Between 0.190 inches and 0.210 inches

Maximum Power Dissipation Rating:

1.2 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Eo lorops

Features Provided:

Bipolar and programmed and monolithic and electrostatic sensitive

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Bipolar metal-oxide semiconductor

Input Circuit Pattern:

16 input

Criticality Code Justification:

Feat

Case Outline Source And Designator:

D-8 mil-m-38510

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, programmed

Voltage Rating And Type Per Characteristic:

-0.5 volts total supply and 7.0 volts total supply

Memory Device Type:

Pal

Special Features:

Esd; altered item programmed using 67268/5962-8515509rx using file 1055_u8.Jed with check sum f8e4

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 printed circuit

NSN 5962-01-367-1275

Memory Microcircuit - Page 2 of 2



Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0